

2019 Applied Materials Technical Symposium in Korea

A New Era of Memory Technology

January 25, COEX Seoul, 3F, Room 318

Time	Title	Presenter
11:45 - 13:00	Registration / Lunch	
13:00 - 13:10	Welcome	Mukund Srinivasan, Applied Materials
13:10 - 13:45	DRAM Challenges and Future	Shigeru Shiratake, Micron
13:45 - 14:10	Materials Engineering Driven Solutions for Advanced DRAM Technology	Sean Kang, Applied Materials
14:10 - 14:25	Break	
14:25 - 15:00	3D Flash Memory Overview – Cell Structure, Operations, and Scaling Challenges	Ryota Katsumata, Toshiba Memory
15:00 - 15:25	Vertical Scaling Paths of 3D NAND Technology	Tomohiko Kitajima, Applied Materials
15:25 - 16:00	Electrification and Vehicle Intelligence Pioneer the Intelligent Mobility	Haruyoshi Kumura, Nissan Motor
16:00 - 16:05	Conclusion	SW Lee, Applied Materials